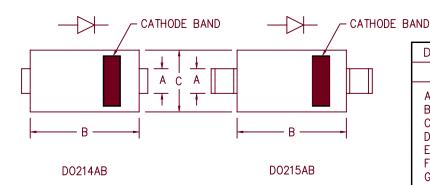
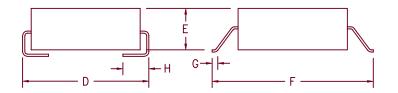
<u>тыбы 3 Amp Schottky Rectifier</u> 5820SM — 5822SM



Dim. Inches			Millimeter		
	Minimum	Maximum	Minimum	Maximum	Notes
Α	.117	.123	2.97	3.12	
В	.260	.280	6.60	7.11	
С	.220	.245	5.59	6.22	
D	.307	.322	7.80	8.18	
Ε	.075	.095	1.91	2.41	
F	.380	.400	9.65	10.16	
G	.025	.040	.640	1.02	
Н	.030	.060	.760	1.52	



Microsemi Catalog Number	Working Peak Reverse Voltage	Repetitive Peak Reverse Voltage
5820SM*	20V	20V
5821SM*	30V	30V
5822SM*	40V	40V
*Add Suffix J For	J Lead or G For Gull Wir	g Lead Configuration

- Schottky Barrier Rectifier
- Guard Ring Protection
- Low Forward Voltage
- High Reliability
- High Current Capability
- Surface mount package

Flootrioal	Characteristics
Electrical	Characteristics

		<u>5820SM</u>	<u>5821SM</u>	<u>5822SM</u>	
Average forward current Maximum surge current Max peak forward voltage Max peak forward voltage Max peak forward voltage Max peak reverse current Typical junction capacitance	IF(AV) IFSM VFM VFM VFM IRM CJ	3A 150A .36V .46V .65V 1.5mA 265pF	3A 150A .37V .48V .67V 1.5mA 265pF	3A 150A .38V .50V .70V 1.5mA 265pF	Square wave, $^{T}L = 127^{\circ}C$, $^{R}\Theta JL = 20^{\circ}C/W$ 8.3ms, half sine, $^{T}J = 150^{\circ}C$ $^{I}FM = 1A$, $^{T}J = 25^{\circ}C^{*}$ $^{I}FM = 3A$, $^{T}J = 25^{\circ}C^{*}$ $^{I}FM = 9.4A$, $^{T}J = 25^{\circ}C^{*}$ ^{V}RRM , $^{T}J = 25^{\circ}C$ $^{V}R = 5.0V$, $^{T}J = 25^{\circ}C$

*Pulse test: Pulse width 300 µsec, Duty cycle 2%

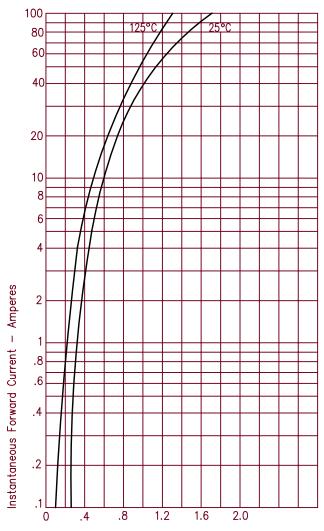
Thermal and Mechanical Characteristics

Storage temperature range TSTG -55°C to 150°C
Operating junction temp range TJ -55°C to 150°C
Maximum thermal resistance ROJL 20°C/W Junction to Lead
Weight .008 ounces (.22 grams) typical

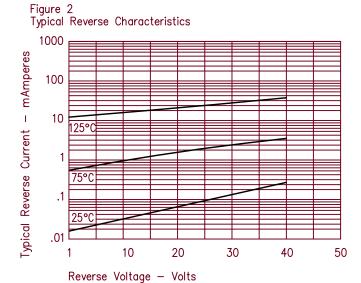


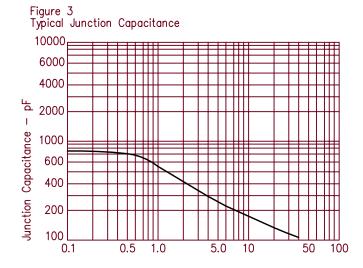
5820SM - 5822SM

Figure 1 Typical Forward Characteristics



Instantaneous Forward Voltage — Volts





Reverse Voltage - Volts